

## Strain effects in multiferroic heterostructures

M. E. Gomez

*Thin Film Group, Department of Physics and Center of Excellence on Novel Materials, CENM,  
Universidad del Valle, Cali, Colombia.*

*Email: [maria.gomez@correounivalle.edu.co](mailto:maria.gomez@correounivalle.edu.co)*

web site: <http://fisica.univalle.edu.co/index.php/profesores>; [www.cenm.org](http://www.cenm.org)

In multiferroic heterostructures magneto electric coupling between a ferroelectric and a ferromagnetic material has been extensively studied during the last decade and various interaction mechanisms have been identified as promising routes towards exclusively electric-field controlled magnetism. In this work, we report the magnetic anisotropy in strain-coupled systems. We have systematically growth ferromagnetic (FM)  $\text{La}_{2/3}\text{Sr}_{1/3}\text{MnO}_3$  ( $t_{\text{LSMO}}=100$  nm) / ferroelectric (FE)  $\text{BaTiO}_3$  ( $t_{\text{BTO}}=100$  nm), (LSMO/BTO), bilayers on (001) oriented  $\text{SrTiO}_3$  (STO),  $(\text{LaAlO}_3)_{0.3}(\text{Sr}_2\text{TaAlO}_6)_{0.7}$  (LSAT), and  $\text{LaAlO}_3$  (LAO) substrates as a possible route to design heterostructures with artificial magnetolectric coupling. We have analyzed samples via X-ray reciprocal space map revealing that LSMO grew epitaxially strained whereas the BTO film grew relaxing its single-crystal structure through dislocations formed in the LSMO-BTO interface. Samples also exhibited ferromagnetic order with magnetization between 280-320  $\text{emu/cm}^3$  at 300 K, making possible multiferroic behaviour at room temperature. We realized magnetization hysteresis loops at 300 K, with the magnetic field ( $H_{\text{app}} = 5$  kOe) applied along different in-plane crystallographic directions for magnetic anisotropy analysis. Results show that bilayer grown on STO substrate exhibits a change in the magnetic anisotropy from biaxial magnetic ordering (observed in the LSMO/STO single-layer) to uniaxial magnetic ordering, probably due to strain induced by the BTO layer on the top of LSMO layer. This effect is not observed in the bilayers grown on LSAT and LAO substrates. This result revealed that the superficial strain effect only induced a uniaxial anisotropy when the LSMO films is grown under tensile strain.

**Acknowledgments:** We thank *Instituto de Nanociencias de Aragon (INA)* for supporting growth and measurements of samples. This work has been supported by Center of Excellence on Nobel Materials–CENM, Research Projects: *CI7917-CC 10510 contract 0002-2013 COLCIENCIAS and CI 7978 UNIVALLE.*